



RF Power Module

Power = 50.0 Watts

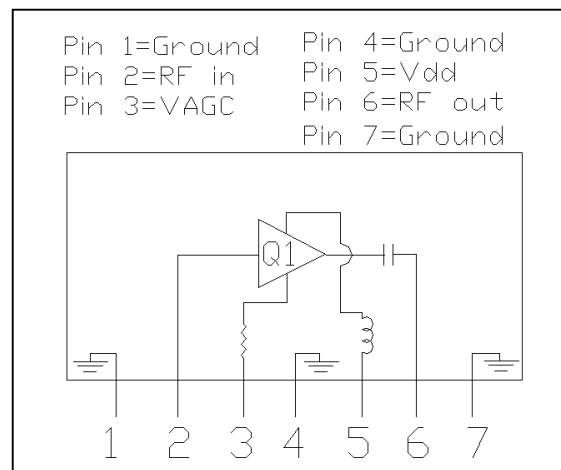
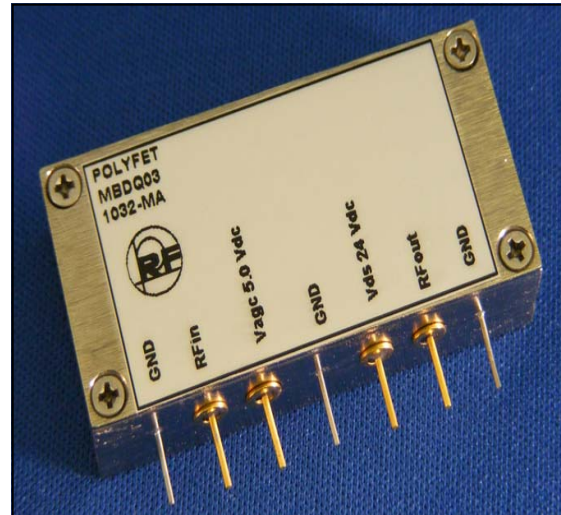
Bandwidth = 30 to 512 Mhz

Gain = 10.0 dB Vdd =24.0 Volts

50 ohms Input/Output Impedance

Description

The MBDQ03 is a 50 Watt, single stage amplifier module covering a bandwidth of 30-512 Mhz. This compact module design is suitable for military applications in a rugged environment. An ALC pin out is provided to control the output power, gain and blanking of the module.



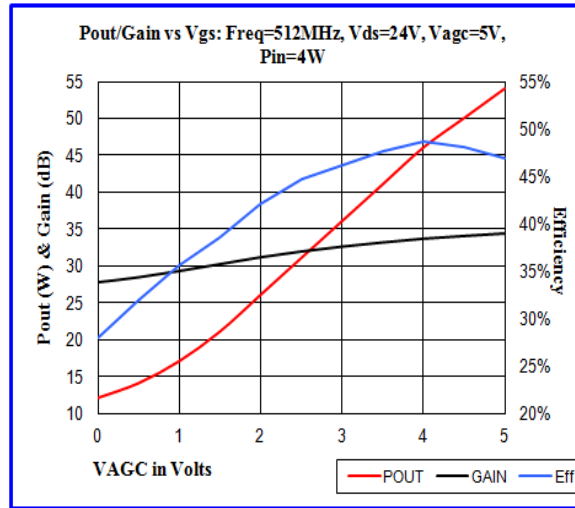
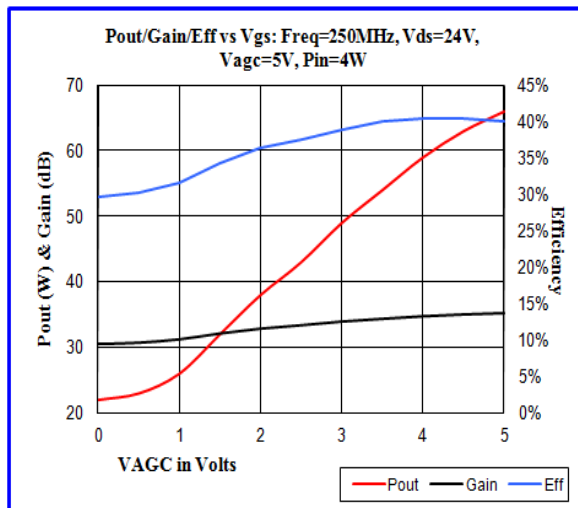
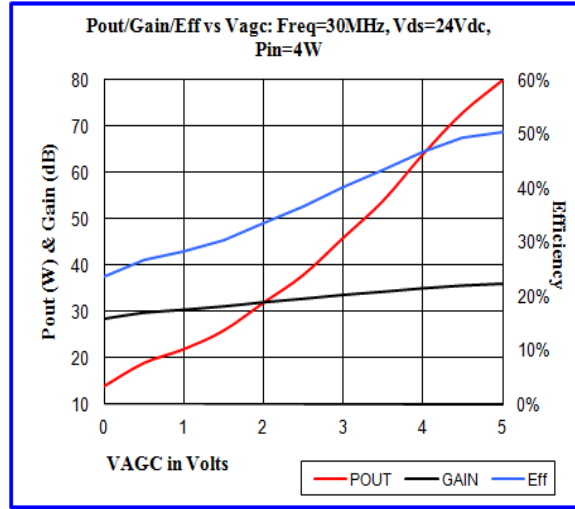
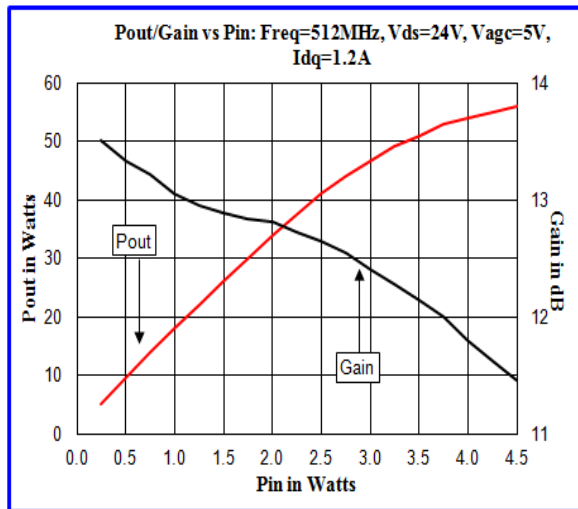
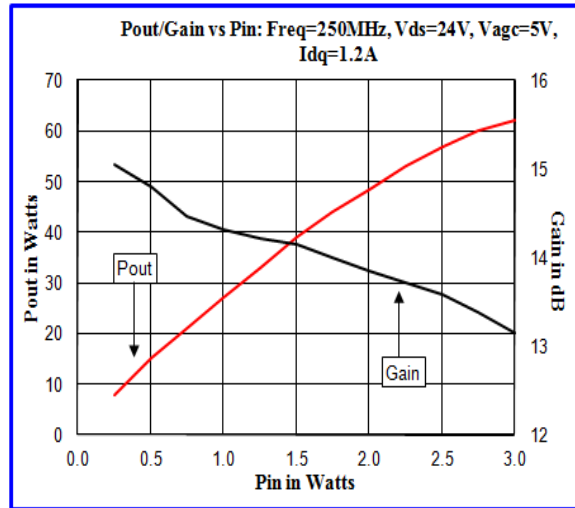
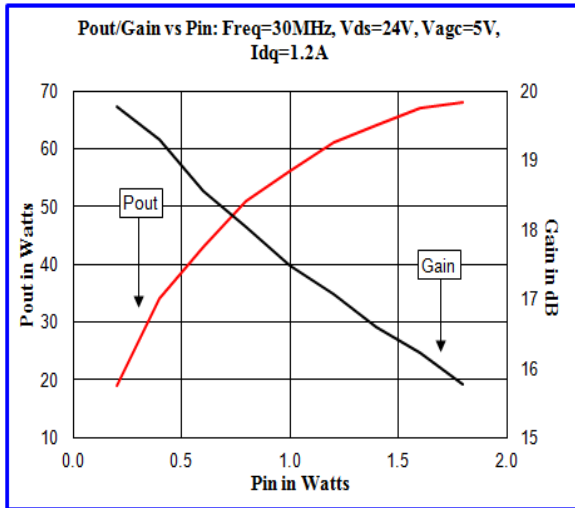
Absolute Maximum Ratings (T=25 °C)

Parameter	Symbol	Value	Unit
DC supply Voltage 1	VDD1	32.0	V
DC supply Voltage 2	VDD2		V
AGC Voltage	VAGC	5.5	V
AGC Current	VAGCI	2.50	mA
Input Power	Pin	5.000	W
Output Power	Pout	65.0	W
Operating Case Temp.	Tc	-40 to +85	°C
Storage Temperature	Tstg	-55 to +100	°C

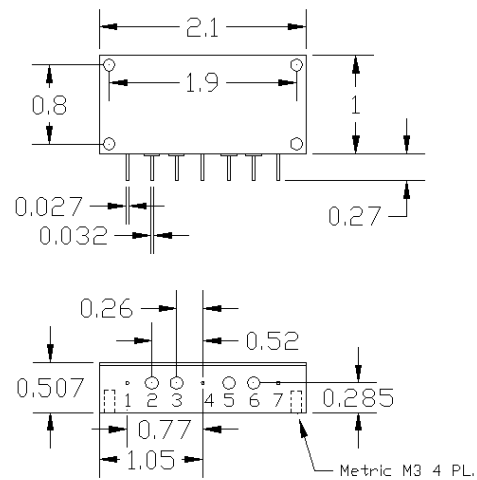
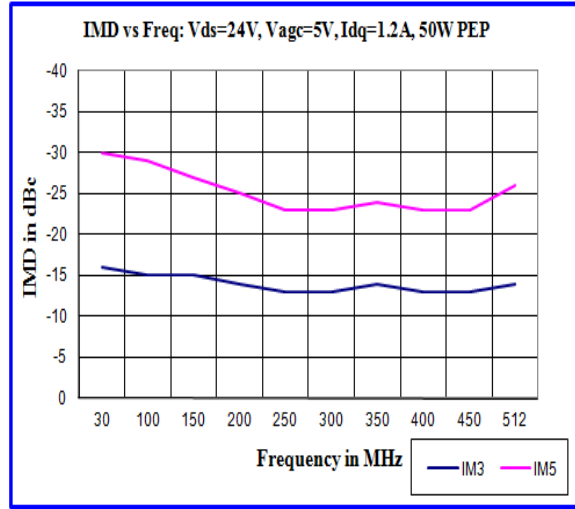
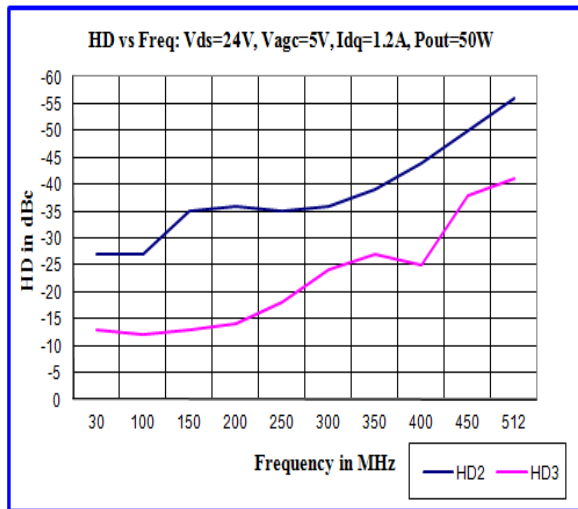
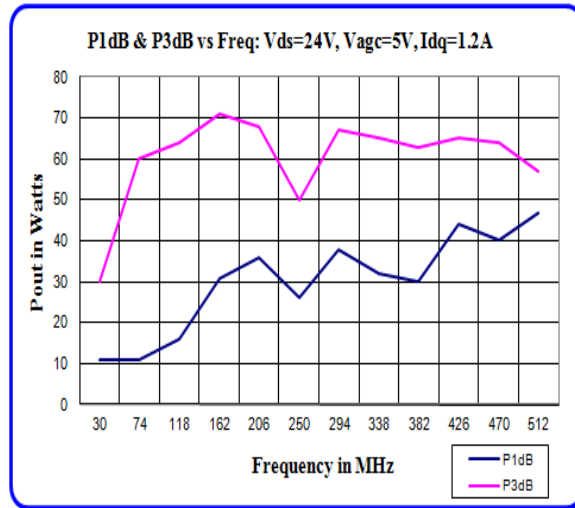
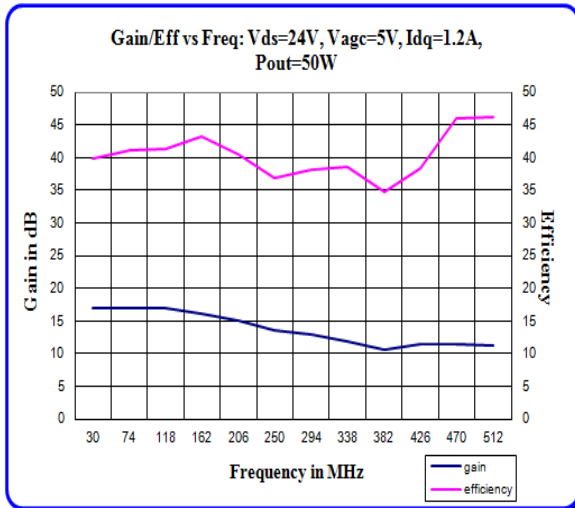
Electrical Characteristics: (T=25 °C Zs=Zl=50 ohms, Vdd = 24.0 Volts, Idq = 1.2 Amps)

Parameter	Symbol	Min	Typical	Max	Unit	Test Conditions
Frequency Range	BW	30		512	Mhz	50 ohm load
Output Power	Po	50.0			Watts	Pin = 37.0 dbm Vagc = 5.0 V
Power Gain	PG	10.0			dB	Pout = 50.0 Watts Vagc = 5.0 V
Total Efficiency	η		40		%	Pout = 50.0 Watts
2nd Harmonics	dso	-25.00	-35.00		dBc	Pout = 50.0 Watts @ Mhz
Intermod - 2 tone	Im3		-15.00		dBc	AvePwr= 25.0 Watts
Load Mismatch Tolerance	VSWR	10:1			Relative	All Phase Angles Pout = 50.0Watts
Vagc Voltage	VAGC			5.0	V	Pin = 37.0 dBm, Pout = 50.0 W
Pulse Response Time	Pr				uS	Pulse source: Vagc

MBDQ03



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POLYFET RF DEVICES

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1110 Avenida Acaso, Camarillo, Ca 93012 Tel:(805) 484-4210 FAX: (805) 484-3393 URL:www.polyfet.com